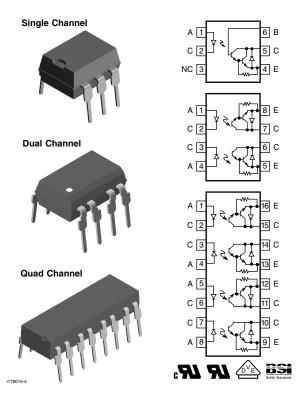
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Optocoupler, Photodarlington Output, with Internal RBE (Single, Dual, Quad Channel)



FEATURES

- · Internal RBE for high stability
- Four available CTR categories per package type



• Standard DIP packages

 Material categorization: For definitions of compliance please see www.vishay.com/doc?99912





COMPLIAN

DESCRIPTION

IL66, ILD66, and ILQ66 are optically coupled isolators employing gallium arsenide infrared emitters and silicon photodarlington detectors. Switching can be accomplished while maintaining a high degree of isolation between driving and load circuits, with no crosstalk between channels.

AGENCY APPROVALS

- UL1577, file no. E52744 system code H, double protection
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- BSI IEC 60950, IEC 60065

ORDERING INFORMATION							
I L x 6 6	-	# CTR BIN	X 0 PACKAGE	# #	TAPE AND	DIP-#	Option 6
x = D (Dual) or Q (Quad)					REEL	Option 7	Option 9

	SINGLE C	CHANNEL DUAL CHANNEL		QUAD CHANNEL					
AGENCY CERTIFIED/ PACKAGE	CTR (%)								
TAGINGE			2	2 mA			0.7 mA	2 mA	
UL, cUL, BSI	≥ 100	≥ 300	≥ 300	≥ 500	≥ 100	≥ 300	≥ 400	≥ 500	
DIP-6	IL66-1	IL66-2	-	-	-	-	-	-	
DIP-8	-	-	ILD66-2	ILD66-4	-	-	-	-	
SMD-8, option 7	-	-	-	ILD66-4X007T	-	-	-	-	
SMD-8, option 9	-	-	-	ILD66-4X009	-	-	-	-	
DIP-16	-	=	-	-	ILQ66-1	ILQ66-2	ILQ66-3	ILQ66-4	
SMD-16, option 7	-	-	-	-	-	-	-	ILQ66-4X007T	
SMD-16, option 9	-	-	-	-	-	-	-	ILQ66-4X009T	
VDE, UL, cUL, BSI	≥ 100	≥ 300	≥ 300	≥ 500	≥ 100	≥ 300	≥ 400	≥ 500	
DIP-6, 400 mil, option 6	IL66-1X016								
DIP-16								ILQ66-4X001	

Note

Additional optiony may be possible, please contact sales office.



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT				
INPUT	· ·								
Peak reverse voltage			V _{RM}	6.0	V				
Forward continuous current			I _F	60	mA				
Power dissipation			P _{diss}	100	mW				
Derate linearly from 25 °C				1.33	mW/°C				
OUTPUT	· ·								
Power dissipation			P _{diss}	150	mW				
Derate from 25 °C				2.0	mW/°C				
COUPLER	· ·								
Isolation test voltage	t = 1.0 s		V _{ISO}	5300	V _{RMS}				
		IL66	P _{tot}	250	mW				
Total package power dissipation		ILD66	P _{tot}	400	mW				
		ILQ66	P _{tot}	500	mW				
		IL66		3.3	mW/°C				
Derate linearly from 25 °C		ILD66		5.33	mW/°C				
		ILQ66		6.67	mW/°C				
Creepage distance				≥ 7.0	mm				
Clearance distance				≥ 7.0	mm				
Comparative tracking index			CTI	175					
Indiation variations	V _{IO} = 500 V, T _{amb} = 25 °C		R _{IO}	≥ 10 ¹²	Ω				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C		R _{IO}	≥ 10 ¹¹	Ω				
Storage temperature			T _{stg}	- 55 to + 125	°C				
Operating temperature			T _{amb}	- 55 to + 100	°C				
Lead soldering time at 260 °C				10	s				

Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 20 mA	V_{F}		1.25	1.5	V
Reverse current	V _R = 6.0 V	I _R		0.1	10	μΑ
Capacitance	V _R = 0 V	Co		25		pF
ОИТРИТ						
Collector emitter breakdown voltage	I _C = 1.0 mA, I _F = 0 A	BV _{CEO}	60			V
Collector base breakdown voltage (IL66)	$I_C = 10 \mu\text{A}$	BV _{CBO}	60			V
Collector emitter leakage current	$V_{CE} = 50 \text{ V}, I_F = 0 \text{ A}$	I _{CEO}		1.0	100	nA
Capacitance collector emitter	V _{CE} = 10 V			3.4		pF
COUPLER						
Saturation voltage, collector emitter	$I_C = 10 \text{ mA}, I_F = 10 \text{ mA}$	V _{CEsat}		0.9	1.0	V

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.



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CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT									
	1 00 A V 10 V	IL(D,Q)66-1	CTR	100	400		%		
Current transfer ratio	$I_F = 2.0 \text{ mA}, V_{CE} = 10 \text{ V}$	IL(D,Q)66-2	CTR	300	500		%		
Current transfer ratio	$I_F = 0.7 \text{ mA}, V_{CE} = 10 \text{ V}$	IL(D,Q)66-3	CTR	400	500		%		
	$I_F = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	IL(D,Q)66-4	CTR	500	750		%		

SWITCHING CHARACTERSITICS (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
NON SATURATED									
Rise time -1, -2, -4	V_{CC} = 10 V, I_F = 2.0 mA, R_L = 100 Ω	t _r			200	μs			
Fall time -1, -2, -4	V_{CC} = 10 V, I_F = 2.0 mA, R_L = 100 Ω	t _f			200	μs			
Rise time -3	V_{CC} = 10 V, I_F = 0.7 mA, R_L = 100 Ω	t _r			200	μs			
Fall time -3	V_{CC} = 10 V, I_F = 0.7 mA, R_L = 100 Ω	t _f			200	μs			

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

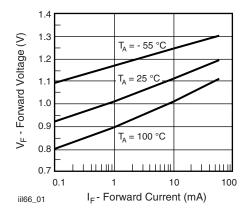


Fig. 1 - Forward Voltage vs. Forward Current

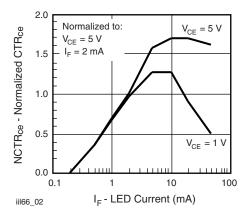


Fig. 2 - Normalized Non-Saturated and Saturated CTR $_{\rm CE}$ vs. LED Current

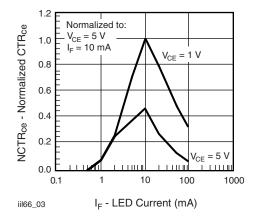


Fig. 3 - Normalized Non-Saturated and Saturated CTR $_{\rm CE}$ vs. LED Current

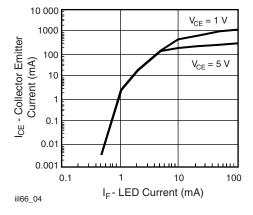


Fig. 4 - Non-Saturated and Saturated Collector Emitter Current vs. LED Current

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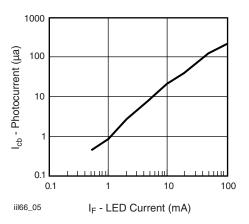


Fig. 5 - Collector Base Photocurrent vs. LED Current

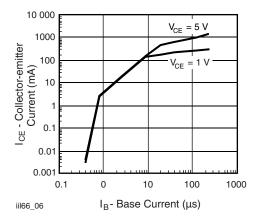


Fig. 6 - Collector Emitter Current vs. LED Current

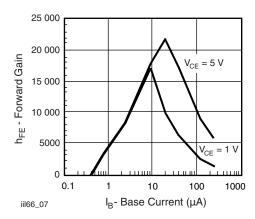


Fig. 7 - Non-Saturated and Saturated h_{FE} vs. LED Current

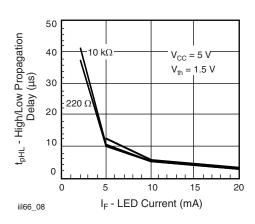


Fig. 8 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

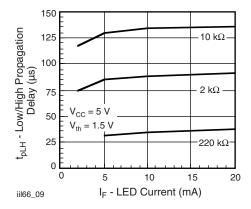


Fig. 9 - Low to High Propagation Delay vs. Collector Load Resistance and LED Current

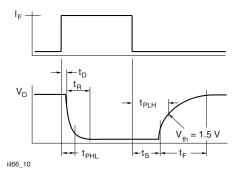


Fig. 10 - Switching Waveform

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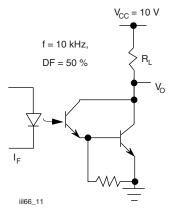
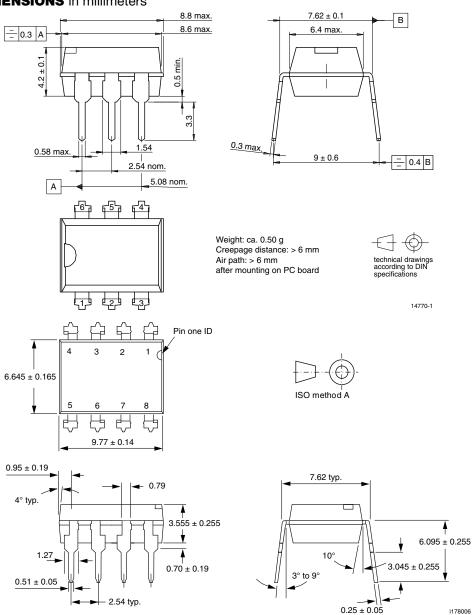


Fig. 11 - Switching Schematic

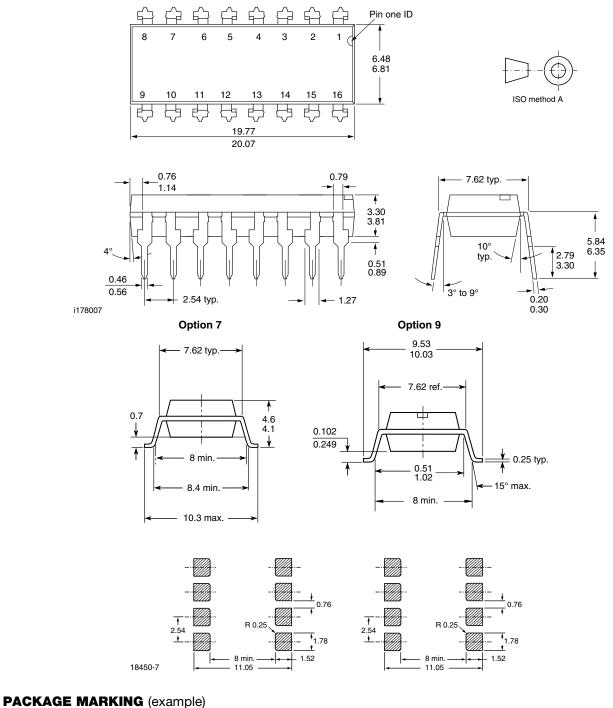
PACKAGE DIMENSIONS in millimeters



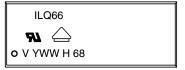


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Notes

- Only options 1 and 7 reflected in the package marking
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking



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